

Title (en)

MIXED BISMUTH AND COPPER OXIDES AND SULPHIDES FOR PHOTOVOLTAIC USE

Title (de)

WISMUT/KUPFER-MISCHOXIDE UND SULFIDE ZUR VERWENDUNG IN DER PHOTOVOLTAIK

Title (fr)

OXYDES ET SULFURES MIXTES DE BISMUTH ET CUIVRE POUR APPLICATION PHOTOVOLTAÏQUE

Publication

**EP 2901495 A2 20150805 (FR)**

Application

**EP 13776438 A 20130930**

Priority

- FR 1202589 A 20120928
- EP 2013070350 W 20130930

Abstract (en)

[origin: WO2014049172A2] The present invention relates to the use of a material comprising at least one compound of formula (I):  $\text{BiCu}1-z\text{OaSbSecTed}$  (I), where  $0 \leq z \leq 0.2$ ;  $0 \leq a \leq 2$ ;  $0 \leq b \leq 2$ ;  $0 \leq c \leq 2$ ;  $0 \leq d \leq 2$ ; and  $a + b + c + d = 2$ , as a p-type semiconductor, for providing a photocurrent. The invention also relates to the photovoltaic devices using these semiconductors.

IPC 8 full level

**H01L 31/032** (2006.01); **C01B 19/00** (2006.01); **C01G 29/00** (2006.01); **H01L 31/072** (2012.01)

CPC (source: CN EP US)

**C01B 19/002** (2013.01 - CN EP US); **C01B 19/007** (2013.01 - CN EP US); **C01G 29/006** (2013.01 - CN EP US); **H01G 9/2027** (2013.01 - CN EP US); **H01L 21/02472** (2013.01 - CN EP US); **H01L 21/02565** (2013.01 - CN EP US); **H01L 21/02568** (2013.01 - CN EP US); **H01L 21/0259** (2013.01 - CN EP US); **H01L 21/02628** (2013.01 - CN EP US); **H01L 31/0272** (2013.01 - US); **H01L 31/032** (2013.01 - CN EP US); **H01L 31/072** (2013.01 - CN EP US); **C01G 29/00** (2013.01 - CN EP US); **C01P 2002/52** (2013.01 - CN EP US); **C01P 2006/40** (2013.01 - CN EP US); **H01L 21/02614** (2013.01 - CN EP US); **H01L 21/02631** (2013.01 - CN EP US); **Y02E 10/542** (2013.01 - EP US)

Citation (search report)

See references of WO 2014049172A2

Designated contracting state (EPC)

AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO PL PT RO RS SE SI SK SM TR

Designated extension state (EPC)

BA ME

DOCDB simple family (publication)

**WO 2014049172 A2 20140403**; **WO 2014049172 A3 20141002**; CN 104813483 A 20150729; EP 2901495 A2 20150805; FR 2996355 A1 20140404; FR 2996355 B1 20160429; JP 2016500624 A 20160114; KR 20150065753 A 20150615; US 2015221794 A1 20150806

DOCDB simple family (application)

**EP 2013070350 W 20130930**; CN 201380061780 A 20130930; EP 13776438 A 20130930; FR 1202589 A 20120928; JP 2015533628 A 20130930; KR 20157010582 A 20130930; US 201314429474 A 20130930